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High Strength and High Electrical Conductivity Al Nanocomposites for DC Transmission Cable Applications

Abdolreza Javadi [1,†], Shuaihang Pan [1,†], Chezheng Cao [2] and Xiaochun Li [1,2,*]

1   Scifacturing Laboratory, Department of Mechanical and Aerospace Engineering, University of California, Los Angeles, CA 90095, USA; javadi@g.ucla.edu (A.J.); luckypsh@g.ucla.edu (S.P.)
2   Department of Materials Science and Engineering, University of California, Los Angeles, CA 90095, USA; cheercao@g.ucla.edu
*   Correspondence: xcli@seas.ucla.edu
†   These authors contribute equally to this paper.

Abstract: Aluminum is one of the most abundant lightweight metals on Earth with broad practical applications, such as in electrical wires. Although traditional aluminum manufacturing by alloying, deformation and thermomechanical means addresses the balance between high strength and high conductivity, adding metallic ceramic nanoparticles into the aluminum matrix can be an exciting alternative approach to mass produce aluminum electrical wires. Here, we show a new class of aluminum nanocomposite electrical conductors (ANECs), with significantly higher hardness (130 HV) and good electrical conductivity (41% IACS). This ANEC is composed of Al and dispersed TiB_2 nanoparticles, as confirmed by XRD scanning and SEM imaging. We further observed an unusual ultra-fine grain (UFG) size when slow cooling ANEC samples, as a grain as small as 300 nm was clearly captured in FIB images. We believe that the significant hardness enhancement can be partially attributed to the UFG. Our investigation and theoretical analysis further validated that UFG can be achieved when nanoparticles are uniformly dispersed and distributed in the aluminum matrix, and this understanding is important for the development of Al nanocomposite wires with high strength and high electrical conductivity.

Keywords: aluminum; electrical conductivity; nanocomposites; ultra-fine grain

1. Introduction

Pure aluminum and its alloys have been widely used for overhead electrical direct current (DC) transmission lines [1–5]. These metallic systems offer good mechanical and moderate electrical properties. However, these cables suffer from excessive weight, high electricity loss, and poor thermal stability. Aluminum conductor steel-reinforced cable (ACSR) is the most common electrical conductor cable used for transmission lines [5–7]. In the USA, it is estimated that annual electricity transmission and distribution losses are about 5% [8], which can be translated into about USD 24 billion. In addition, the tower cost for such a high-density electrical cable can be significant [5]. ACSR consists of Al 1350-H19 strands responsible for electrical conductivity and a high-strength steel wire core that carries the weight of the whole cable system. ACSR suffers from high electrical resistivity, high density, and low temperature stability.

The strengthening mechanisms of metallic systems, such as sever plastic deformation (e.g., cold drawing, equal-channel angular pressing) [9–12], high-pressure torsion [13–15], accumulated roll bonding [16–18], solid solution treatment [19–22], grain boundary strengthening (Hall–Petch effect) [23], dislocation strengthening, precipitation strengthening [24], and solid solution strengthening [25], cannot meet the demands of the new generation of electrical wires. Several material systems have been proposed to produce aluminum electrical wires via powder metallurgy methods, such as Al–Nb [26], Al–Ti [27], Al–Mg [28], Al–Sn [29], and Al–Ca [5]. Although these proposed solutions have

demonstrated improved strength, they suffer from poor electrical conductivity and, more importantly, small-scale production (e.g., powder metallurgy). Nanoparticle-reinforced metal is a class of hybrid material that offers unusual properties [30–32]. Thus, incorporating suitable nanoparticles into the aluminum matrix can be a viable and scalable approach to producing aluminum electrical conductors for high-voltage DC transmission lines. Incorporating suitable nanoparticles into an Al matrix unusually enhances the mechanical strength while retaining reasonable electrical conductivity. The nanocomposite approach is an exciting opportunity to synthesize Al nanocomposites to achieve mechanical and electrical properties beyond the limits posed by traditional manufacturing techniques.

In this paper, we developed an easily-synthesized Al–TiB$_2$ nanocomposite. The microstructure and phase composition have been checked to confirm the successful fabrication of Al nanocomposites with various vol.% values of well-dispersed TiB$_2$. The microhardness and electrical conductivity tests in this study show the potential of using this Al–TiB$_2$ nanocomposite for electrical applications (i.e., its electrical conductivity is >80% of its pure counterpart, while increasing the strength). The aim of this research is to provide a facile fabrication method for scalable Al–TiB$_2$ nanocomposites, and to obtain a fundamental understanding of the effects of nanoparticle dispersion on processing quality, increased strength, and balanced electrical performance.

2. Materials and Methods

Materials synthesis. In this study, TiB$_2$ was selected as the nano-reinforcement since it is an extremely hard ceramic. High-purity Al (99.99% purity, from American Elements Co. Ltd., Los Angeles, CA, USA) ingots and in-house-synthesized TiB$_2$ nanoparticles with an average size less than 8 nm were used as the matrix and nano-reinforcement, respectively. [33] TiB$_2$ nanoparticles and KAlF$_4$ (with the purity >98%, from Domydo Co. Ltd., Hebei, China) flux were mechanically mixed in the solid state for 3 h. The mixed powders were dehydrated at 120 ℃ for 1 h in a vacuum oven (NRTL Certified 25L 200C Vacuum Oven from MTI Corporation, Richmond, CA, USA). An electrical resistance furnace (115 volts, 860 watts from Thermcraft, Inc., Winston-Salem, NC, USA) was then used to melt the Al ingots isothermally at 850 ℃ under argon (Ar) gas (from Airgas, Los Angeles, CA, USA) flow protection. The mixed powders were gradually added to the melt surface and the melt was mechanically stirred at 200 rpm for 10 min with a one-inch diameter titanium (Ti) mixing blade. The melt was naturally cooled down to room temperature under Ar gas protection. The final product was (in the shape of a disk with a 1.5-inch diameter and 1.0-inch height) carefully extracted from the graphite crucible (from Eforlife, USA via Amazon online purchase). Figure 1 shows the schematic of the experimental setup. Al–X vol.% TiB$_2$ (X=3, 5, and 10) nanocomposites were produced (three study samples were prepared from the top, middle, and bottom of each nanocomposite sample).
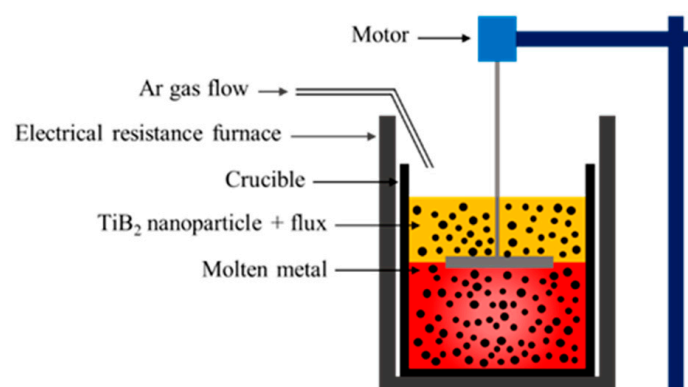

Figure 1. Schematic of the flux-assisted liquid state processing experimental setup.

Characterization. Scanning electron micrographs (SEM) were acquired using a *ZEISS Supra 40VP* field emission microscope (from CNSI, Los Angeles, CA, USA) operating at 10

kV, and the EDS mapping was conducted on the same machine. During the EDS element mapping, Al K and Ti K peaks were used for characterization. X-ray diffraction scanning was conducted on a Panalytical Pro XRD machine (from MIC Facilities, Los Angeles, CA, USA), with the scanning voltage of 45 KV and scanning current of 40 mA. The step speed was set to 1°/min. FIB machining and characterization were conducted on a *Nova 600 FIB* system (FEI) (from NanoLab Facilities, Los Angeles, California, USA). The microhardness was measured on an *LM 800AT* microhardness tester (by Leco Inc., St. Joseph, MI, USA). The loading was set to 200 gf with a dwelling time of 10 s. The microhardness results were taken as an average of 10 measurements for each point. Electrical conductivity was measured by *CDE ResMap 178* 4-Point Probe (from NanoLab Facilities, Los Angeles, CA, USA). The electrical conductivity results were taken as an average of 5 measurements.

3. Results and Discussion

Figure 2 shows the Vickers hardness versus electrical conductivity (%IACS) result for pure Al as well as Al–TiB$_2$ nanocomposites with three different volume concentrations of TiB2 nanoparticles Al matrix. The Vickers hardness and electrical conductivity of the as-cast pure Al were measured to be 25±3 HV and 63±3.5% IACS (2.8 μΩ.cm), which are set as the reference points for the Al–TiB$_2$ system. Both the tests were carried out at room temperature (25 °C) with a constant humidity of about 38%. As the volume percent of the nanoparticles increased, the hardness of the Al nanocomposite became higher due to the addition of the hard TiB$_2$ ceramic nanoparticles. On the other hand, TiB$_2$ nanoparticles acting as electron scattering centers in the Al nanocomposite caused electrical conductivity reduction. With 3, 5, and 10 vol.% TiB$_2$ in the aluminum matrix, the electrical conductivity of the nanocomposite samples was 58.0%, 43.6%, and 40.5% IACS, respectively. Compared with other similar Al alloy systems [1,3], our nanocomposites, even with over 3 vol.% TiB$_2$, could offer a higher electrical conductivity, which demonstrates their advantages and great potential in electrical conductor applications.
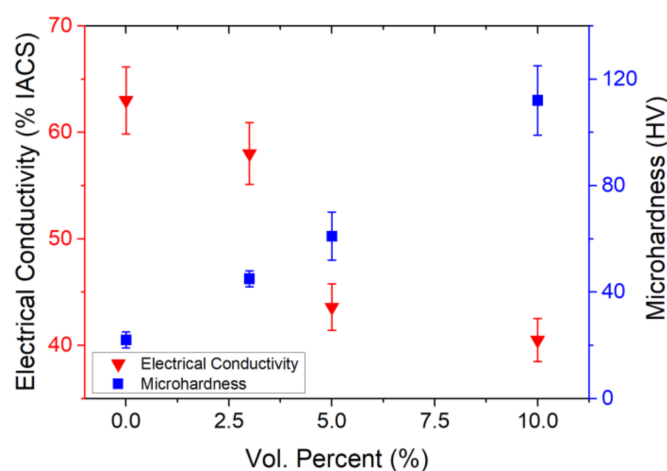

Figure 2. Effect of TiB$_2$ nanoparticles on mechanical and electrical properties of Al–TiB$_2$ nanocomposites.

Electrical conductivity. Classical electrical conductivity theory is based on the free electrons that move throughout the lattice of the metal. Considering Drude's free electron theory [34], electrons are free to move in every direction within the metal lattice by following Newton's laws of motion and Maxwell–Boltzmann statistics [35]. The electrical resistivity and electron mean-free path of a given metal are constant values. MFP is inversely proportional to the electron scattering probability. The electron's interaction with the lattice and inclusion (defect) promotes electron scattering, consequently leading to increases in electrical resistivity. According to Matthiessen's rule, the electrical resistivity of metals is the summation of two main parts: thermal (ρ_T) and residual (ρ_R). ρ_T refers to the direct effect of environmental temperature on the electrons in the metal. The ρ_R

is associated with the microstructure of the metallic systems that contribute to electron scattering, such as lattice scattering, impurity scattering, precipitate scattering, and grain boundary scattering [36,37]. When comparing the conventional strengthening mechanism approaches, one can conclude that electron scattering and consequently electrical conductivity reduction are inevitable. For metals such as Al, the electrical conductivity analysis can be carried out with the Drude model under the expression:

$$S_0 = \frac{n\tau e^2}{m^*} \tag{1}$$

where S_0 indicates the matrix's electrical conductivity without nanoparticle incorporation under the same temperature condition. τ is the relaxation time of the free mobile electrons in the matrix, corresponding to MFP; e is the charge every electron carries; m^* denotes the effective mass of the electrons. n is the number density of the electron, which is the key parameter to determine the electrical conductivity in our model. According to Nordheim's rule [38,39], the electrical conductivity of the nanocomposites can be written as:

$$\frac{1}{S} = \frac{1}{S_0} + k_1 x(1-x) + k_2 x \tag{2}$$

where S is the electrical conductivity of the nanocomposite, k_1 represents the nanoparticle–metal interaction and k_2 corresponds to the effects of the nanoparticles as a secondary phase in electrical conductivity. x is the nanoparticle volume fraction.

Figure 3 presents a schematic of the electrons pathway inside a metal matrix nanocomposite. The topographical impedance on the current density pathway will block the transport of electrons, as shown in Figure 3. At the macroscopic level, k_2 (~0.23505 uOhm–cm in our case) will be greater than k_1 (~0.00797 uOhm–cm in our case) (especially when $x < 0.2$). This is because the nanoparticles' interaction with the matrix is negligible (both physically, such as the Gibbs free energy change, the interfacial energy change, and the phase transition energy, and chemically, such as the chemical reactions and the electronic structure's tuning) [40]. As a result, the nanoparticle phase will play a dominant role in the electrical conductivity of the nanocomposite. Furthermore, the valences of the electrons are different in the metal Al and the ceramic TiB_2, which leads to deviation from the approximate linearity of the electrical resistivity associated with $k_2 x$ for the electrical conductivity and nanoparticles volume fraction, as shown in Figure 3.
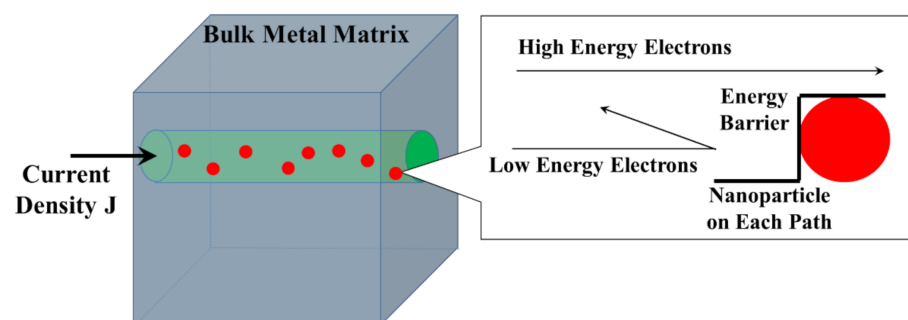

Figure 3. The schematic illustration of the scattering mechanisms in the Al–TiB_2 nanocomposite system (the left side indicates the structural impedance caused by nanoparticle incorporation, whereas the right side demonstrates the interfacial energy barrier formed by Al and TiB_2).

Another important reason is the interfacial scattering along the metal and nanoparticle boundaries. This is supported by the sharp slope of change in the electrical conductivity in the nanocomposite samples with around 3 vol.% to 5 vol.% of TiB_2 nanoparticles (Figure 1), which indicates that the interface must have played a more and more significant role when the incorporated nanoparticles reached a certain volume percent. In the case of higher volume fractions (~ 3 vol.% to 5 vol.%) of nanoparticles in the matrix, the transporting

electrons have a greater chance of encountering the energy barrier between the metal matrix and nanoparticles. Therefore, the electrical conductivity drops more severely. This scattering is mainly due to the interfacial contact. Al and TiB_2 have free electrons at different energy levels and different electronic band structures [40,41], and the interface of these two will present an energy difference that scatters the mobile electrons [41,42]. When lower-energy electrons encounter the Al–TiB_2 interface, they will be scattered during transport, which reduces the electrical conductivity of the nanocomposite due to the band mismatch at the interface [40,42,43].

Since TiB_2 acts as a second phase in the Al matrix and has mobile free electrons with different energy levels in different electronic structures, a decaying trend in the electrical conductivity is expected. However, even for an Al system with up to 10 vol.% TiB_2, as in our case, about 43% IACS electrical conductivity is still very high, and it is thus suitable for many electrical applications.

Ultra-fine grain in the nanocomposite. We first characterized the distribution and dispersion of the TiB_2 nanoparticles in an as-casted Al–TiB_2 nanocomposite sample using scanning electron microscopy. To clearly reveal the nanoparticles, the SEM samples were cleaned via low-angle ion milling (10°, to remove the nanometer-sized polishing powders). SEM images of the Al–TiB_2 nanocomposite are shown in Figure 4. Figure 4a shows the high volume fraction of the TiB_2 nanoparticles uniformly dispersed and distributed in the aluminum matrix. Higher-magnification SEM images illustrate that the TiB_2 nanoparticles retain their original size with any chemical sintering (Figure 4b).
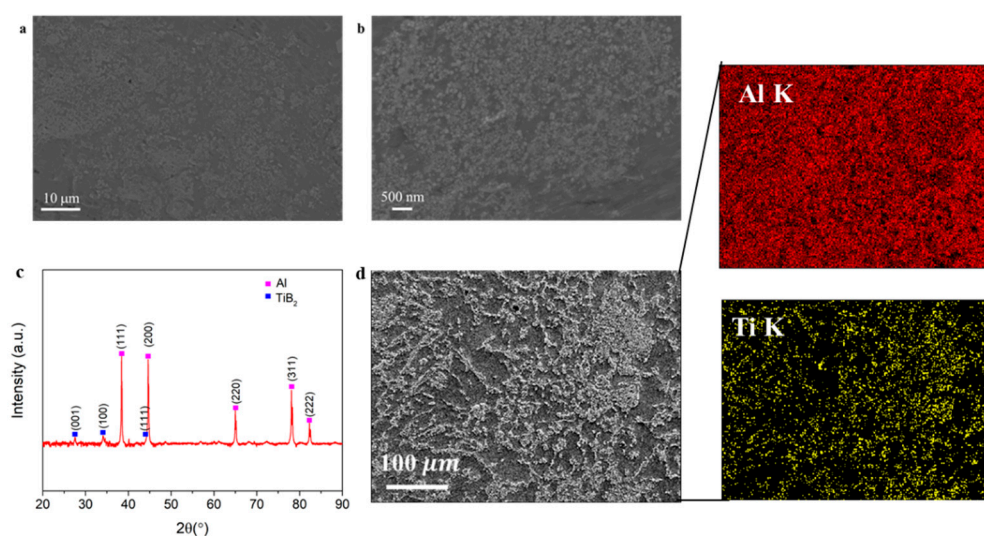

Figure 4. Electron microscopy study. (**a**) SEM images of the Al–TiB_2 nanocomposite samples. (**b**) Higher-magnification SEM images obtained from the Al–TiB_2 nanocomposites. (**c**) XRD scanning results to confirm the phases in Al–TiB_2 (Al–3 vol.% TiB_2 as an example). (**d**) EDS mapping for the Al–TiB_2 nanocomposites (Al–5 vol.% TiB_2 as an example) after ion milling to expose the TiB_2 zone.

A focused ion beam (FIB) was used to cut several aluminum nanocomposite samples. The bottom surface of the aluminum nanocomposite samples revealed a surprising phenomenon. The size of the grain in the as-cast aluminum nanocomposite sample reached ultra-fine grain size under a low cooling rate. The smallest grain size observed was about 300 nm. This unusual phenomenon is attributed to the presence of the nanoparticles acting both as nucleation sites and more importantly pinning down the growth of the aluminum grain, thus enabling it to obtain ultra-fine grain sizes. Figure 5a shows the thin cross-sectional sheet of aluminum nanocomposite milled via FIB. Figure 5b shows high-magnification SEM images clearly representing the nanosized aluminum grains attained in slow cooling.
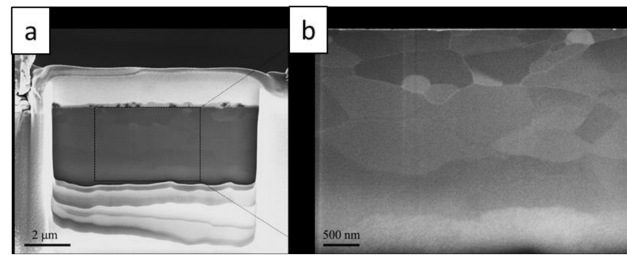
Figure 5. Focused ion beam. (**a**) Aluminum–TiB$_2$ nanocomposite sample sheet prepared by FIB. (**b**) High-magnification SEM images obtain from the rectangular box (from **a**) vividly showing the ultra-fine-grain aluminum.

Nanoparticle dispersion mechanism. In our nanoparticle–molten metal model system, nanoparticles are assumed to be uniformly distributed and dispersed in a molten metal (Figure 4). For simplicity, only interactions between two identical nanoparticles in a molten metal are considered. Figure 6 shows a schematic of two identical nanoparticles (e.g., TiB$_2$) in a static molten metal (e.g., molten Al at 850 °C). For our model we assumed: (1) nanoparticles with a radius R are spherical in shape and D is the gap between two nanoparticles; (2) there was no macroscopic convection in the melt; (3) there was negligible electrostatic interaction or double layers between the nanoparticles and molten metal; (4) there were negligible buoyancy and gravity forces acting on the nanoparticles; (5) there was no severe chemical reaction between the nanoparticles and molten metal, and (6) there was no gas film or contamination on the nanoparticles' surfaces.
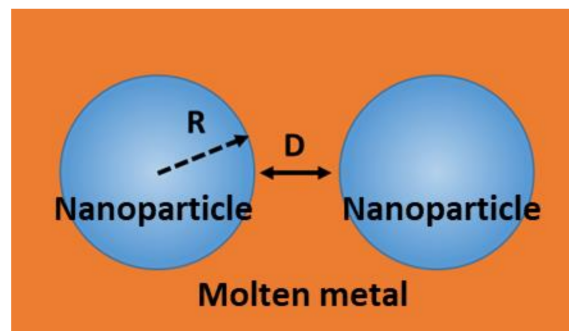

Figure 6. Model for two identical nanoparticles interacting in a molten metal.

Based on the above assumptions, three major interactions—interfacial energy, van der Waals potential, and Brownian potential—are considered in this model system.

When two nanoparticles interact in a molten metal far apart from each other, the interfacial energy is:

$$G_b = 2S_{pl}\sigma_{pl} \tag{3}$$

where S_{pl} is the surface area of a nanoparticle and σ_{pl} is the interfacial energy between the nanoparticle and molten metal. If the two nanoparticles travel toward each other to push all metal atoms out and create a void between them, the interfacial energy would be:

$$G_b = 2(S_{pl} - S_{pp})\sigma_{pl} + 2S_{pp}\sigma_p \tag{4}$$

where S_{pp} and σ_p are the effective contact area and the surface energy of the nanoparticle, respectively. If the two nanoparticles attain a sufficient adhesive contact to chemically bond (i.e., sintering starts), there will be no physical interface between the two nanoparticles. We consider this global energy minimum to be zero. Therefore, when two nanoparticles move

close enough together to squeeze the metal atoms out and create a void between them, the change in Gibbs free energy can be described as:

$$\Delta G_1 = 2S\left(\sigma_p - \sigma_{pl}\right) \tag{5}$$

where S is the effective contact area. If the nanoparticles move closer together to start chemically bonding with each other, the change in Gibbs free energy can be written as:

$$\Delta G_2 = -2S\sigma_p \tag{6}$$

Since the interfacial energy is always positive, ΔG_2 would always be negative. Hence, the interaction potential of two similar surfaces of a unit area along with the gap between them, D, can be expressed as:

$$W_{inter}(D) = 2S\left(\sigma_p - \sigma_{pl}\right) e^{-(D-D_0)/a_0} \frac{D - a_0}{D_0 - a_0}, \; for \; (D_0 < D < a_0) \tag{7}$$

$$W_{inter}(D) = -2S\sigma_p e^{D/a_0}(1 - D/D_0) + 2S\left(\sigma_p - \sigma_{pl}\right), \; for \; (0 < D < D_0) \tag{8}$$

where D_0 is the chemical length bond, and a_0 is the characteristic decaying length (0.2~0.4 nm) for the chemical bond.

The van der Waals potential between two nanoparticles in a molten metal is of a relatively long range (0.2−9 nm). Nanoparticles tend to attract each other due the attract force induced by van der Waals potential. The van der Waals potential for two identical spheres of radius R_1 is determined by [44,45]:

$$W_{vdw}(D) = -\frac{AR}{12D} \tag{9}$$

where A is the system's Hamaker constant for the nanoparticles' interactions in the molten metal. To estimate the Hamaker constant A, the below equation can be used:

$$A = \left(\sqrt{A_{NP}} - \sqrt{A_L}\right)^2 \tag{10}$$

where A_{NP} is the Hamaker constant for the nanoparticle, and A_L is the Hamaker constant for the metal. Therefore, the van der Waals potential can be written as:

$$W_{vdw}(D) = -\frac{\left(\sqrt{A_{NP}} - \sqrt{A_L}\right)^2}{12D}(R) \tag{11}$$

Since nanoparticles are very small in size, they are free to move randomly under thermal fluctuations. Thus, Brownian potential needs to be considered for these small nanoparticles. The equipartition theorem suggests that the kinetic energy/potential of the Brownian motion is in one dimension for one particle. Therefore, the Brownian motion energy for the two-nanoparticle system in on dimension is kT. For two nanoparticles in a molten metal at high temperatures, it may be comparable to the van der Waals potential, and thus the Brownian potential would play an important role in nanoparticle dispersion.

In the model system for nanoparticle dispersion in a molten metal, the van der Waals potential, interfacial energy, and Brownian potential intrinsically co-exist. The interfacial energy dominates when the gap between two nanoparticles becomes one or two atomic layers. The van der Waals interaction dominates outside this gap up to a great distance (up to 10 nm or more). Hence, three possible cases can be considered for nanoparticle dispersion in a molten metal: clusters, pseudo-dispersion, and self-dispersion. In this study we focus on the self-dispersion case.

Figure 7 shows the interaction potentials for nanoparticle self-dispersion in the molten metal. If $W_{barrier}$ is high (i.e., good wettability between the nanoparticle and the molten

metal) and the van der Waals potential well is not deep, the Brownian potential, kT, cannot cause the nanoparticles to pass the barrier for any adhesive contact, although the nanoparticles would not be kinetically trapped either. This would allow the nanoparticles to move freely without forming a chemical bond to another nanoparticle in the molten metal, which is the so-called self-dispersion.
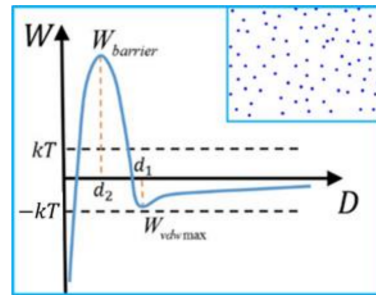

Figure 7. Interaction potentials for nanoparticle self-dispersion in molten metal with an inset to show how nanoparticles disperse in molten metal.

To further validate the self-dispersion model, the Al–TiB$_2$ system was studied. The Hamaker constants for Al and TiB$_2$ are 266zJ and 256zJ [44], respectively. The average size of the TiB$_2$ nanoparticles is 10 nm. Equation (10) is effective only when two TiB$_2$ nanoparticles interact in molten Al, where the D is about 0.4 nm [44]. Therefore, by inserting the values into Equation (10), we get: $W_{vdw}(D) = -4.2zJ$ (4.2×10^{-21} J). The thermal energy value at 820 °C would be 15.11 zJ, which is higher than the van der Waals interaction potential. The surface energies for liquid Al and solid TiB$_2$ are 1.1 J/m^2 [46] and 3.0 J/m^2 [47], respectively, and the contact angle between Al and TiB$_2$ is 80 degrees ($D_0 = 0.1$ nm and $a_0 = 0.4$ nm) at the aforementioned temperature. The effective interaction area, S, is about 15.7 nm^2. We can calculate the W$_{barrier}$ to be 6.8×10^3 zJ. Since the W$_{barrier}$ is more than 500 times greater than the Brownian potential, there is little chance of the TiB$_2$ nanoparticles overcoming the energy barrier and adhering to each other (forming a cluster). Therefore, we can conclude that TiB$_2$ nanoparticles can self-disperse in molten Al. This is in good agreement with our experimental results shown in the result section.

4. Conclusions

In this work, we introduce a novel and scalable approach to produce a new class of aluminum electrical conductor for DC transmission lines. A suitable nanoparticle was identified to significantly improve the mechanical properties of the aluminum matrix while retaining reasonable electrical conductivity. Small TiB$_2$ nanoparticles (less than 10 nm) were effectively incorporated into the aluminum matrix via flux assisted liquid processing. TiB$_2$ nanoparticles were well dispersed and distributed in the aluminum matrix. Al–10 vol.% TiB$_2$ ANEC was successfully produced to offer a Vickers hardness of 130 and an electrical conductivity of 41% IACS. An ultra-fine grain size was achieved in the as-cast samples of nanocomposites. Mechanical property enhancement can be associated with the presence of TiB$_2$ nanoparticles throughout the aluminum matrix, and more importantly, with the formation of ultra-fine aluminum grains. With this understanding, further processing, including extrusion, could be easily applied to the developed Al nanocomposites in order to make the electrical wires. The corresponding degradation behavior and service performance of the Al nanocomposite-based wires should then be assessed. Together with the abovementioned future works, novel Al nanocomposites could be readily utilized in the electrical and electronic fields.

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